

Low Pressure Transducer Fully Temperature Compensated and Calibrated Dual-In-Line Package

## DESCRIPTION

The **SM5650** Series of OEM pressure sensors are fully calibrated, temperature compensated low-pressure sensors in dual in-line packages for printed circuit board mounting. These sensors offer improved performance as well as the option for either constant current or constant voltage excitation.

The SM5600 Series pressure sensors are constructed by attaching a highly stable piezoresistive pressure sensor chip to a ceramic substrate. Thick film resistors on the ceramic are laser trimmed during manufacturing to provide zero offset calibration, temperature compensation for zero offset, and temperature compensation for sensitivity. In the Model SM5651, an additional resistor is trimmed to normalize the output of an external differential amplifier to provide span calibration when the sensor is driven by a constant current supply. In the Model SM5652, a constant voltage supply can be used and the normalized output span of each sensor can then be easily amplified.

The model **SM5651** is designed for constant current excitation.

The model **SM5652** is designed for constant voltage excitation.

Various pressure port configurations are available for flexibility in matching this product to specific applications.



# FEATURES

- Low pressure (from 0-0.15 PSI FS to 0-3.0 PSI FS)
- Constant voltage and constant current versions
- Easy to use dual in-line package (DIP)
- Span calibration to ±2% for low pressure
- Zero offset calibration
- High performance, stable packaged silicon chip
- Gage and differential pressure configurations
- Wide 0-60° C compensated temperature range

## APPLICATIONS

- Medical equipment
- Respiration
- HVAC
- Level detection
- Flow measurement
- Industrial control

40SP5001.02



# SM5651/SM5652 Low Pressure, Constant Current DIP Low Pressure, Constant Voltage DIP

### CHARACTERISTICS FOR SM5651/SM5652 - SPECIFICATIONS

Test Conditions: Model SM5651 w/excitation = 1.500mA @ 25 °C, Model SM5562 w/excitation = 10.00Vdc @ 25 °C, unless otherwise specified. All parameters below for differential parts are defined for top side only. All parameters below for gage parts are defined for back side only.

|                         | Min.  | Тур.  | Max.  | Units       | Notes   |
|-------------------------|-------|-------|-------|-------------|---------|
| Excitation              |       |       |       |             |         |
| Current (SM5651)        | >0    | 1.50  | 3.00  | mA          |         |
| Voltage (SM5652)        | >0    | 10.00 | 20.00 | V           |         |
| Output                  |       |       |       |             |         |
| Span (SM5651)           | 25.0  | 45.0  | 75.0  | mV          | 1       |
| Span (SM5652)           | 24.5  | 25.0  | 25.5  | mV          | 1, 2    |
| Zero Offset             | -2.00 | +0.20 | 2.00  | mV          |         |
| Temperature Performance |       |       |       | -           |         |
| TC Span                 | -0.65 | +0.20 | 0.65  | %FS         | 3       |
| TC Offset               | -1.00 | +0.20 | 1.00  | %FS         | 3       |
| Temp Hysteresis         | -0.30 | +0.05 | 0.30  | %FS         | 4, 7    |
| Accuracy                |       |       |       |             |         |
| Linearity               | -0.30 | +0.05 | 0.30  | %FS         | 5, 7    |
| Repeatability           | -0.30 | +0.05 | 0.30  | %FS         | 7       |
| Pressure Hysteresis     | -0.30 | +0.05 | 0.30  | %FS         | 7       |
| Sensitivity Matching    | -2.00 | -0.20 | +2.00 | %FS         | 1, 6, 7 |
| Impedance (SM5651)      |       |       |       |             |         |
| Z Input                 | 1.80  | 3.00  | 3.80  | kΩ          |         |
| Z Output                | 2.70  | 3.30  | 3.80  | kΩ          |         |
| Impedance (SM5652)      | •     |       | •     |             | •       |
| Z Input                 | 4.50  | 8.00  | 25.00 | kΩ          |         |
| Z Output                | 2.00  | 2.50  | 3.80  | kΩ          |         |
| Temperature Range       |       |       |       |             | 1       |
| Calibration             | +0    |       | +60   | °C          | 3       |
| Operating               | -40   |       | +125  | °C          | 7       |
| Storage                 | -40   |       | +125  | °C          | 7       |
| Dynamic Characteristics | -     |       |       |             | 1       |
| Die Proof Pressure      | 10X   |       |       | FS Pressure | 7       |
| Die Burst Pressure      | 15X   |       | 1     | FS Pressure | 7       |

Notes

Positive Pressure is defined as entry on the bottom side of the die; gain, during factory calibration, is set using negative pressure

For the SM5652, 0.15 PSI range, span is 23.75 (min) to 26.25 (max). Measured over a temperature range of 22 to 58 °C. 2

3.

For 0.15 PSI, TC Span=±2.0%FS; TC Offset=±2.0%FS: For 0.3 PSI. TC Span==±0.75%FS

4. For 0.30 PSI, Hysteresis=±0.45%FS; For 0.15 PSI, Hysteresis=±0.65%FS

5. Best fit straight line; measured from top-side of die For 0.30 PSI, Linearity=±0.5%FS;

For 0.15 PSI, Linearity=±2.5%FS Sensitivity matching relates to part-to-part matching 6.

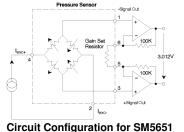
- For 0.15 PSI, Sensitivity Matching=5.0%FS
- 7 Tested on a sample basis

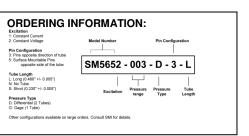
#### Model 5651 Pin-out Model 5652 Pin-Out 1 -Signal Out 1 -Signal Out 2 -lexc 2 -Vexc 3 +Signal Out\* 3 +Signal Out\* 4 +lexc 4 +Vexc

**5 Gainset Resistor** 5 6 Gainset Resistor 6

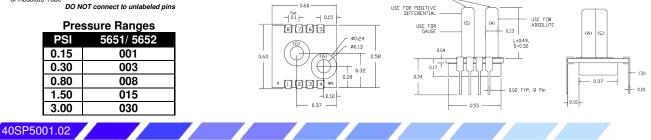
\*Output increases as pressure is increased on Positive Differential Tube

or Absolute Tube





Notes: All dimensions are shown in inches FOR DIFFERENTIAL PRESSURE USE



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Silicon Microstructures, Inc. + 1701 McCarthy Blvd. + Milpitas, CA 95035 USA Tel: 408-577-0100 ♦ Fax: 408-577-0123 ♦ sales@si-micro.com ♦ www.si-micro.com SUNSTAR自动化 http://www.sensor-ic.com/ TEL: 0755-83376489 FAX:0755-83376182 E-MAIL: szss20@163.com



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